TOSHIBA

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX14F,TC74LVX14FN,TC74LVX14FT

Hex Schmitt Inverter

The TC74LVX14F/ FN/ FT is a high-speed CMOS HEX SCHMITT INVERTER fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

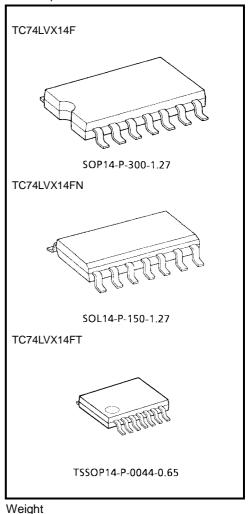
Pin configuration and function are the same as the TC74LVX04 but the inputs have hysteresis and with its schmitt trigger function, the TC74LVX14 can be used as a line receivers which will receive slow input signals.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

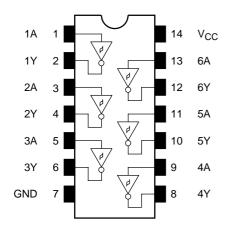
- High-speed: $t_{pd} = 6.8 \text{ ns} (typ.) (V_{CC} = 3.3 \text{ V})$
- Low power dissipation: $ICC = 2 \mu A (max) (Ta = 25^{\circ}C)$
- Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Low niose: VOLP = 0.5 V (max)
- Pin and function compatible with 74HC14

Note: xxxFN (JEDEC SOP) is not available in Japan.



Veight SOP14-P-300-1.27: 0.18 g (typ.) SOL14-P-150-1.27: 0.12 g (typ.) TSSOP14-P-0044-0.65: 0.06 g (typ.)

Pin Assignment (top view)



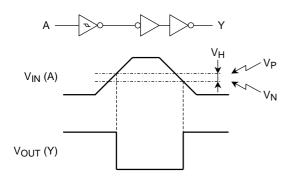
IEC Logic Symbol

1A <u>(1)</u>		(2) (1)
2A (3)	_	(4) 2Y
3A (5)	_	(6) 3Y
4A <u>(9)</u>	_	(8) (10) 4Y
5A (11)		(10) 5Y
6A (13)	-	(12) 6Y

Truth Table

Inputs	Outputs
A	Y
L	н
н	L

System Diagram, Waveform



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	Vout	-0.5 to $V_{CC} + 0.5$	V
Input diode current	IIK	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 3.6	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C

Electrical Characteristics

DC Characteristics

Characteristics Symb		Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
					$V_{CC}(V)$	Min	Тур.	Max	Min	Max	
Threshold	H-level	VP		_	3.0			2.2		2.2	
voltage	L-level	V _N		_	3.0	0.9	_	_	0.9	V	
Hysteresis voltag	e	V _H	_		3.0	0.3		1.2	0.3	1.2	V
Output voltage	V _{OH}		$I_{OH} = -50 \ \mu A$	2.0	1.9	2.0	_	1.9	_		
		$V_{IN} = V_{IL} \\$	I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_		
			$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	_	V	
				I _{OL} = 50 μA	2.0		0	0.1	_	0.1	v
	L-level V _{OL}	$V_{IN} = V_{IH}$	I _{OL} = 50 μA	3.0		0	0.1	_	0.1		
			I _{OL} = 4 mA	3.0			0.36	_	0.44		
Input leakage cur	rent	I _{IN}	$V_{IN} = 5.5 \text{ V or GND}$		3.6			±0.1	_	±1.0	μA
Quiescent supply	current	I _{CC}	$V_{IN} = V_{CC}$ or GND		3.6			2.0		20.0	μA

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol Test Condition				Ta = 25°C			Ta = -40 to 85°C		Unit
			$V_{CC}(V)$	C _L (pF)	Min	Тур.	Max	Min	Max	x
Propagation delay time	+		2.7	15	_	8.7	16.3	1.0	19.5	
	t _{pLH}		2.1	50	_	11.2	19.8	1.0	23.0	ns
	t _{pHL}		3.3 ± 0.3	15	_	6.8	10.6	1.0	12.5	
			5.5 ± 0.5	50	_	9.3	14.1	1.0	16.0	
Output to output skew	t _{osLH}	(Note 1)	2.7	50	_	—	1.5	_	1.5	ns
	t _{osHL}		$\textbf{3.3}\pm\textbf{0.3}$	50	_	—	1.5	_	1.5	115
Input capacitance	C _{IN}			(Note 2)		4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note 3)		21	_		_	pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

- Note 2: Parameter guaranteed by design.
- Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

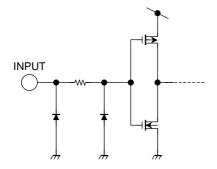
Average operating current can be obtained by the equation: $\log (1 - 2) = C \exp(2) (\cos t \ln 1 + \log 6) (\cos t \sin 2)$

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per gate)

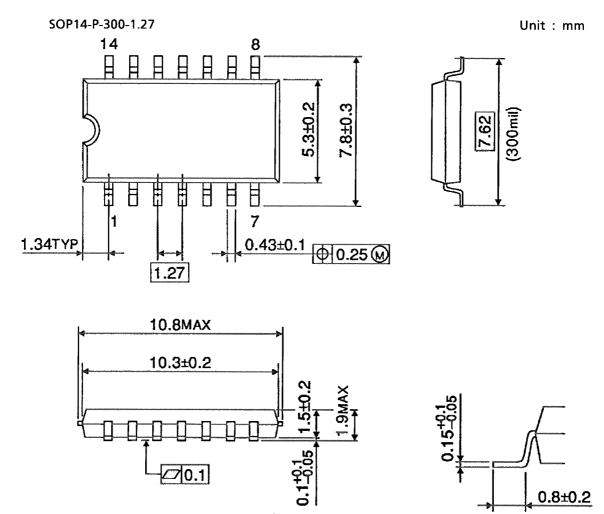
Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$)

Characteristics		Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic	V _{OL}	V _{OLP}	—	3.3	0.3	0.5	V
Quiet output minimum dynamic	V _{OL}	V _{OLV}	_	3.3	-0.3	-0.5	V
Minimum high level dynamic input voltage	VIH	V _{IHD}	_	3.3		2.2	V
Maximum low level dynamic input voltage	VIL	V _{ILD}	—	3.3		0.9	V

Input Equivalent Circuit

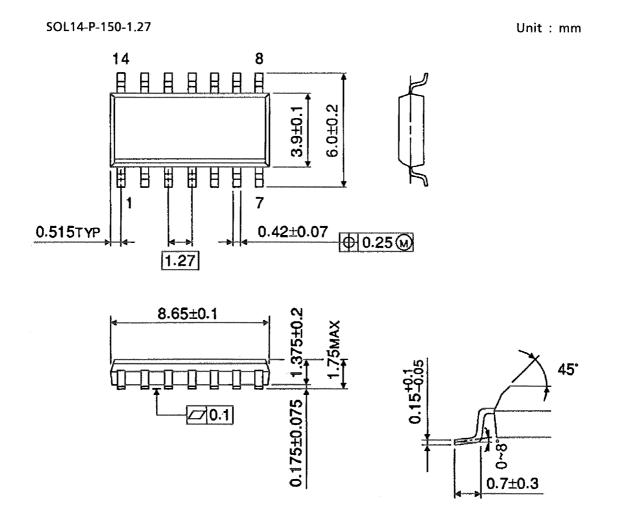


Package Dimensions



Weight: 0.18 g (typ.)

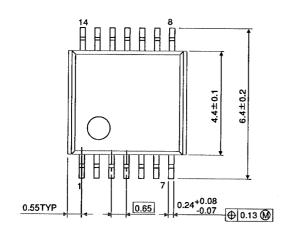
Package Dimensions



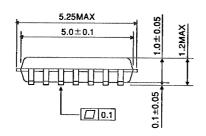
Weight: 0.12 g (typ.)

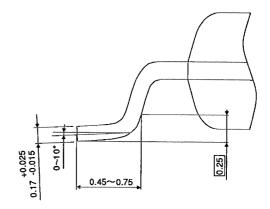
Package Dimensions

TSSOP14-P-0044-0.65









Weight: 0.06 g (typ.)

Unit : mm

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